Photo DMOS-FET Relay

Description

The **LTU520** is a 1-From A and 1-Form B solid state relay in a 8 pin DIP package that employs optically coupled MOSFET technology to provide 3750V of input to output isolation. The optically coupled input is controlled by a highly efficient GaAlAs infrared LED and MOS FETs on the output side.

Features

- Low driver power requirements (TTL/CMOS Compatible)
- No moving parts
- High reliability
- Arc-Free with no snubbing circuits
- 3750Vrms Input/Output isolation

Applications

- Telecommunications (PC, Electronic notepad)
- Measuring and Testing equipment
- Industrial control
- Security equipments
- High speed inspection machine

Outline Dimensions

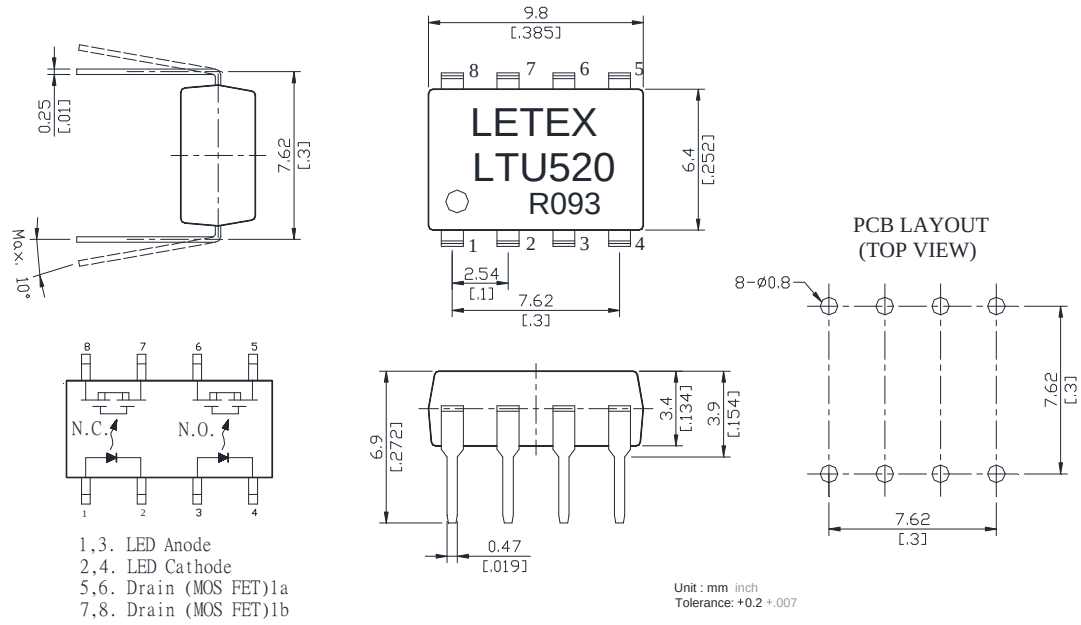


Photo DMOS-FET Relay Specifications

Part Name: LTU520

Absolute Maximum Ratings (Ambient Temperature: 25℃)

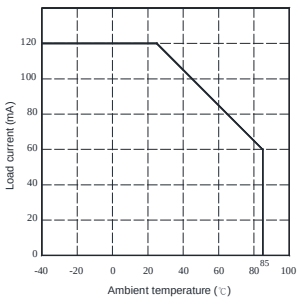
Item		Symbol	Value	Units	Note
Input	Continuous LED Current	IF	50	mA	
	Peak LED Current	IFP	1000	mA	f=100Hz, duty=1%
	LED Reverse Voltage	VR	5	V	
	Input Power Dissipation	PIn	75	mW	
Output	Load Voltage	VL	400	V(AC peak or DC)	
	Load Current	IL	120	mA	
	Peak Load Current	IPeak	0.6	A	1ms(1 pulse)
	Output Power Dissipation	Pout	450	mW	
Total Power Dissipation		PT	500	mW	
I/O Breakdown Voltage		VI/O	3750	Vrms	RH=60%, 1min
Operating Temperature		TOpr	-40 to +85	-40 to +85	
Storage Temperature		TStg	-40 to +100	-40 to +100	
Pin Soldering Temperature		TSol	260	260	10 sec max.

Electrical Specifications (Ambient Temperature: 25℃)

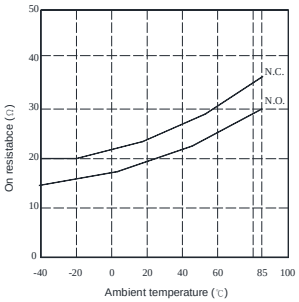
Item		Symbol	MIN.	TYP.	MAX.	Units	Conditions
Input	LED Forward Voltage	V_F		1.2	1.5	V	I_F=10mA
	Operation LED Current	$I_{F\,On}$		0.5	5.0	mA	
	Recovery LED Current	$I_{F\,Off}$		0.35	0.5	mA	
	Recovery LED Voltage	$V_{F\,Off}$	0.5			V	
Output	On-Resistance	R_{On}		20(N.O.)	30(N.O.)	Ω	I_F=5mA (N.O.) I_F=0mA (N.C) I_L=100mA Time to flow is within 1 sec.
				20(N.C.)	50(N.C.)		
	Off-State Leakage Current	I_{Leak}			1(N.O.)	uA	I_F=0mA (N.O.) I_F=5mA (N.C) V_L= Rating
					10(N.C.)		
	Output Capacitance	C_{Out}		150		pF	I_F=5mA,V_L=0, f=1MHz
Transmission	Turn-On Time	T_{On}		0.23(N.O.)	0.5(N.O.)	ms	I_F=5mA, I_L=50mA
				0.2(N.C.)	1.0(N.C.)		
	Turn-Off Time	T_{Off}		0.03(N.O.)	0.2(N.O.)	ms	
				0.5(N.C.)	3.0(N.C.)		
Coupled	I/O Isolation Resistance	$R_{I/O}$	10^{10}			Ω	DC500V
	I/O Capacitance	$C_{I/O}$		0.8		pF	f=1MHz

Reference Data

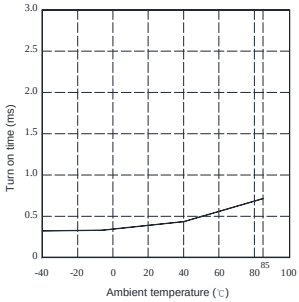
Load current Vs.
Ambient temperature



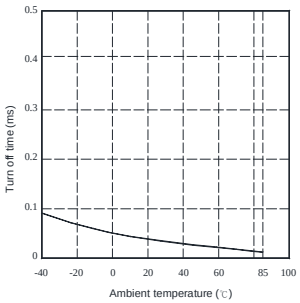
On resistance Vs.
Ambient temperature



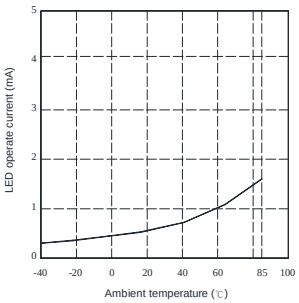
Turn off time Vs.
Ambient temperature



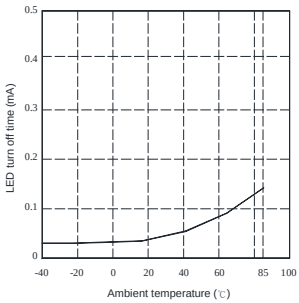
Turn on time Vs.
Ambient temperature



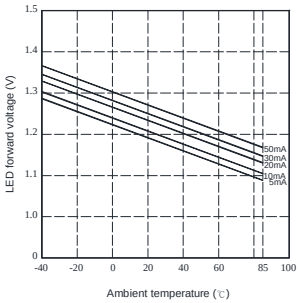
LED operate current Vs.
Ambient temperature



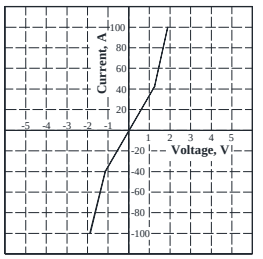
LED turn off current Vs.
Ambient temperature



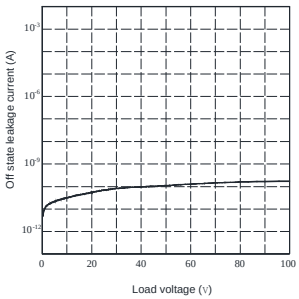
LED forward voltage Vs.
Ambient temperature



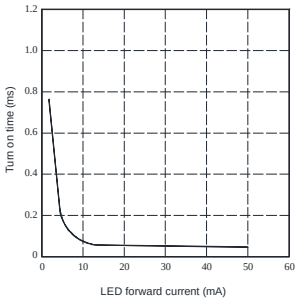
Voltage Vs. currennt characteristics
of output at MOS portion



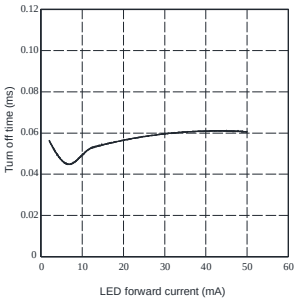
Off state leakage current



LED foward current Vs.
turn on time characteristics



LED foward current Vs.
turn off time characteristics



Applied voltage Vs.
output capacitance characteristics